

Fig. 3

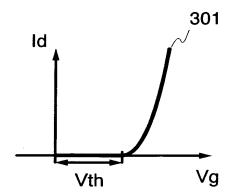
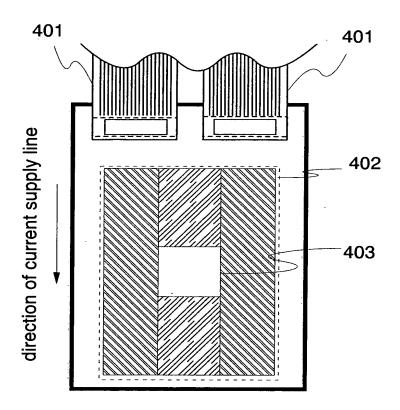
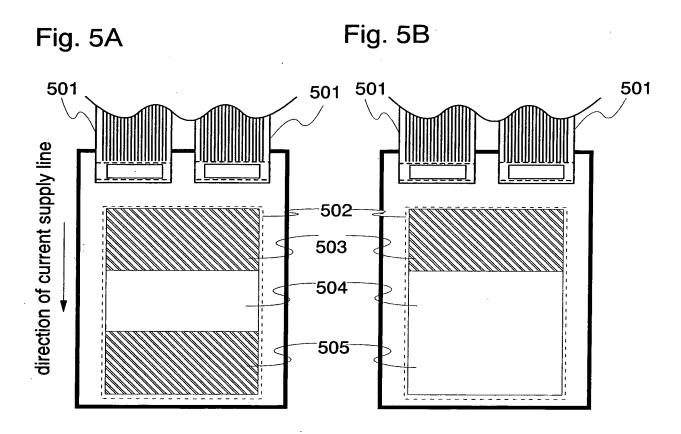
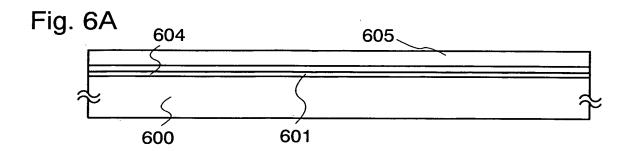
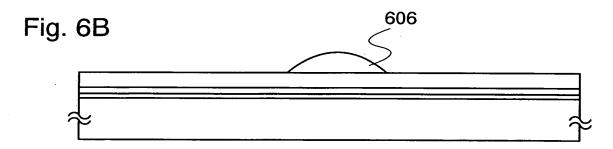


FIG. 4









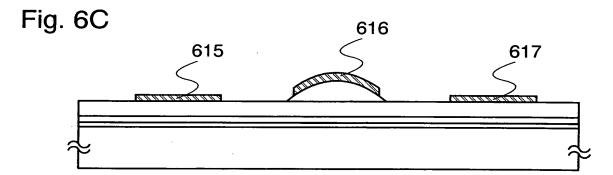


Fig. 7A



Fig. 7B

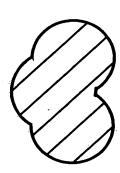


Fig. 7C

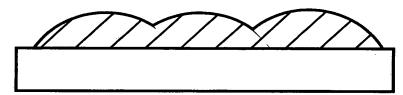
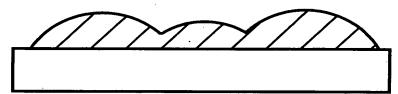
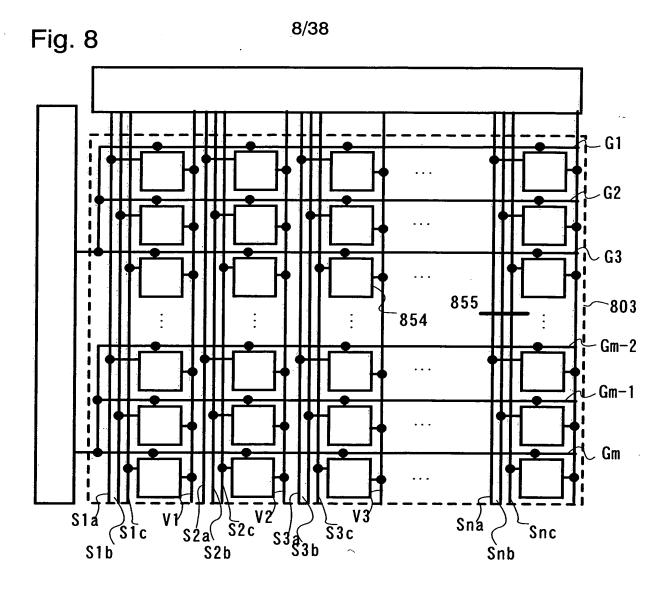


Fig. 7D





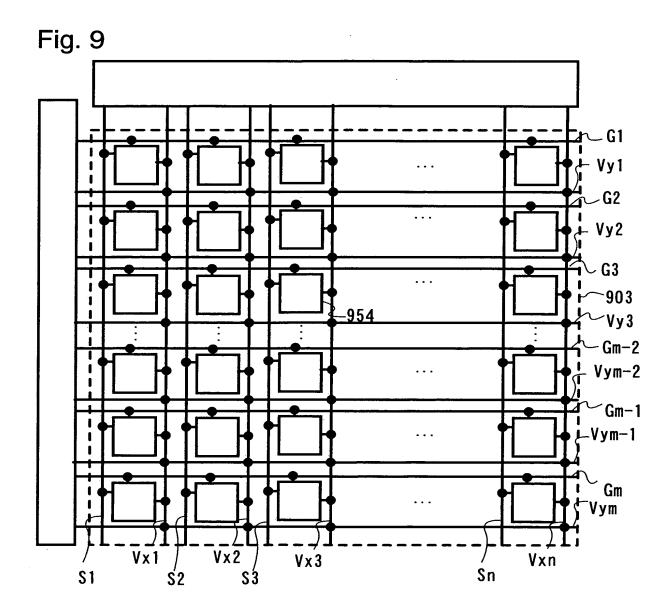


Fig. 10

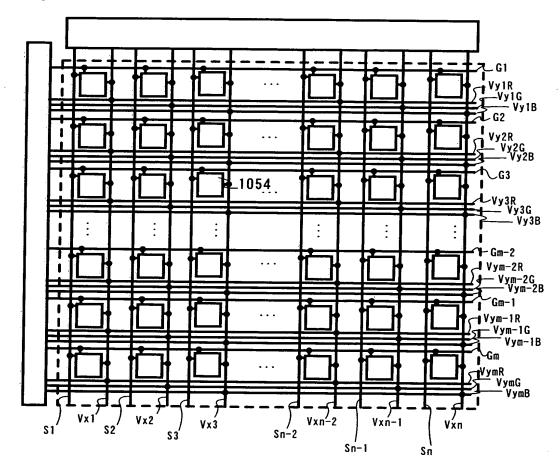


Fig. 11

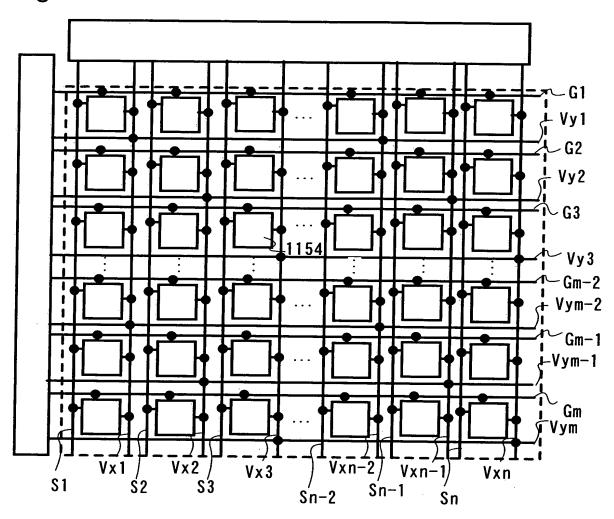
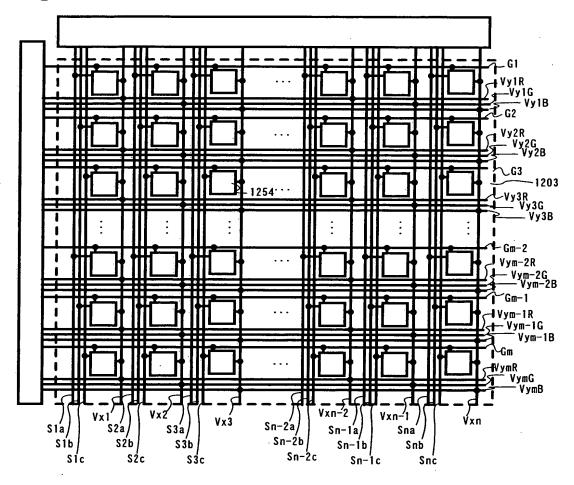
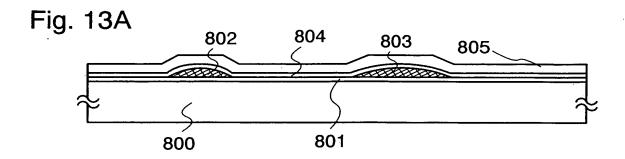
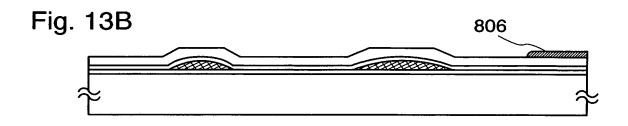
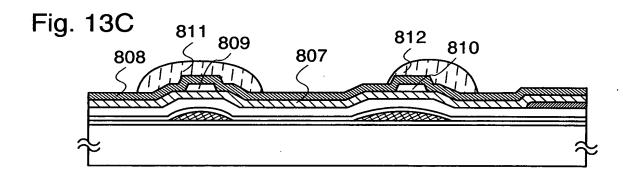


Fig. 12









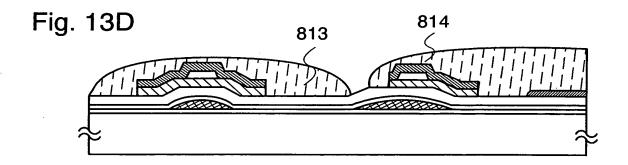


Fig. 14A

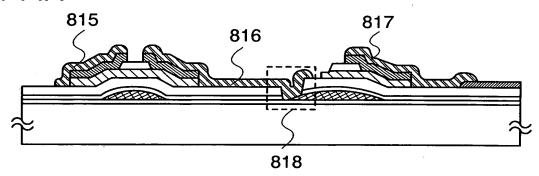
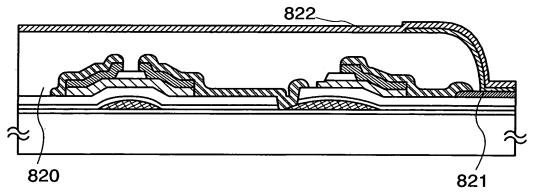
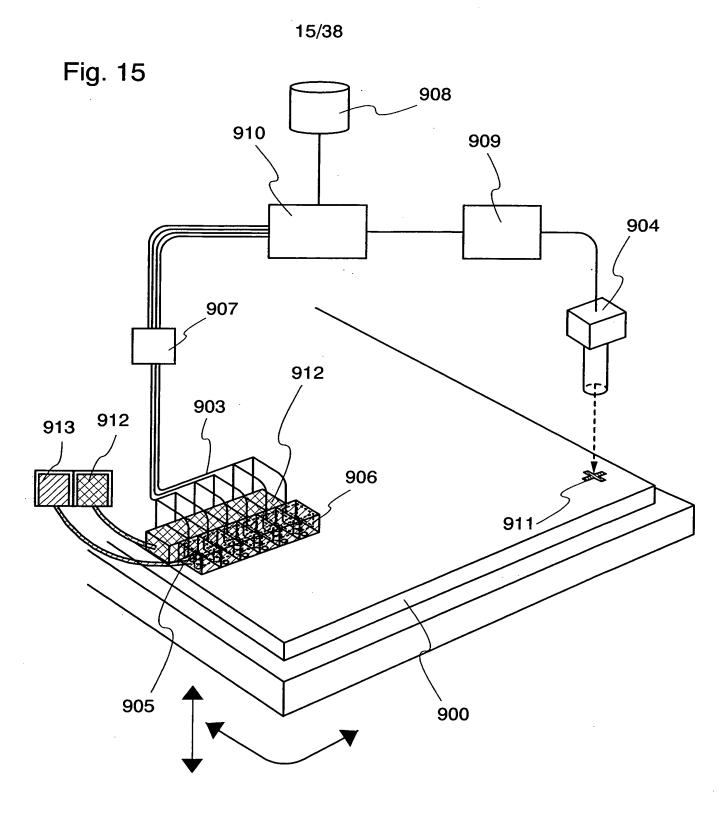


Fig. 14B







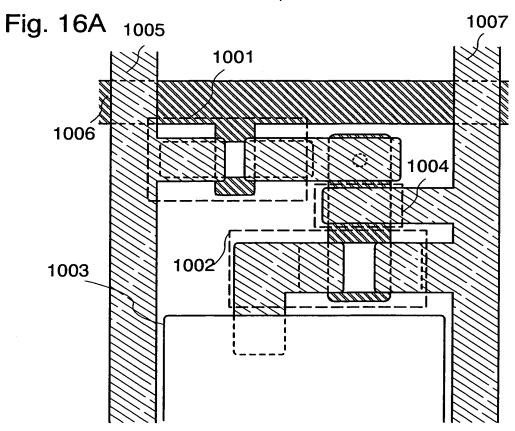
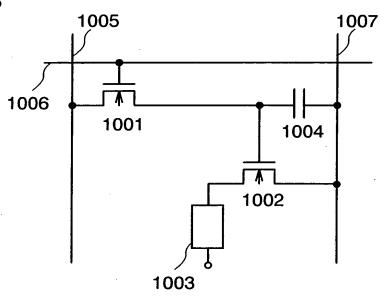
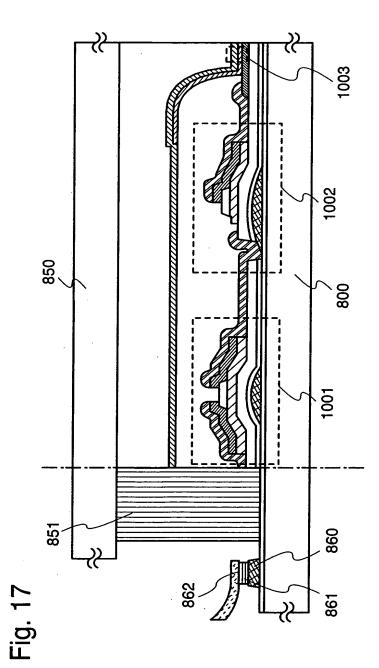
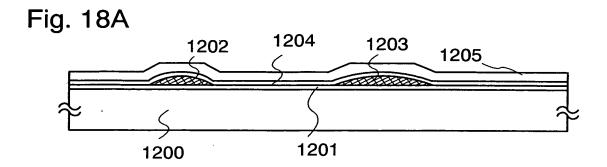
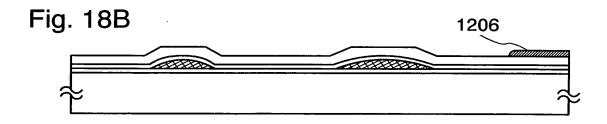


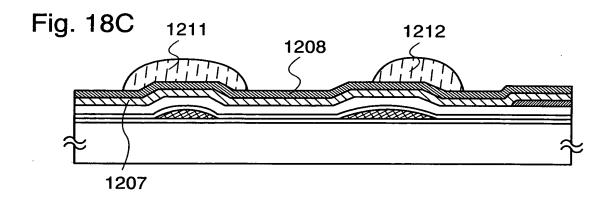
Fig. 16B

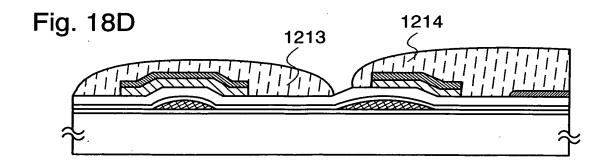


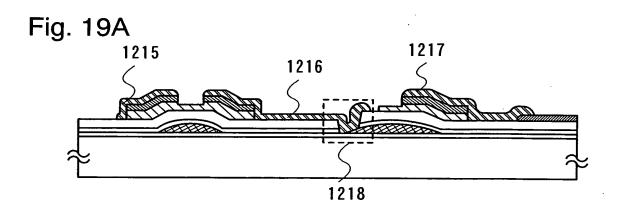












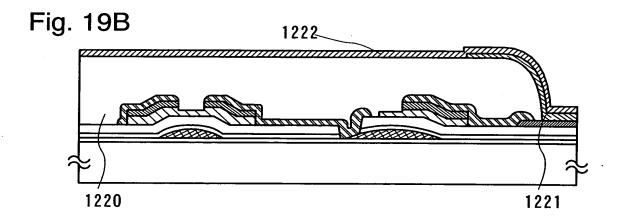


Fig. 20A

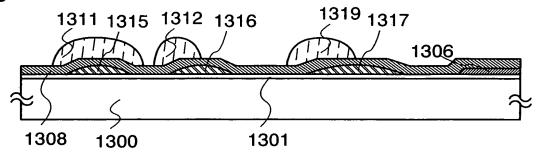


Fig. 20B 1305 1307

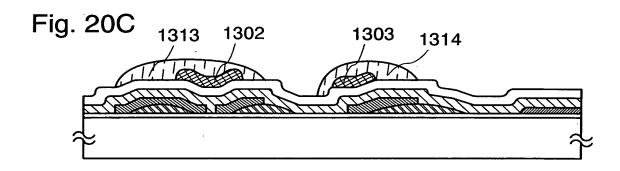


Fig. 20D

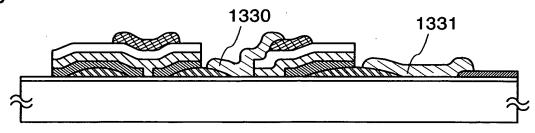
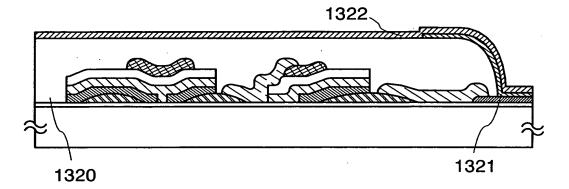
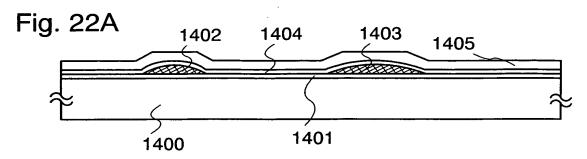
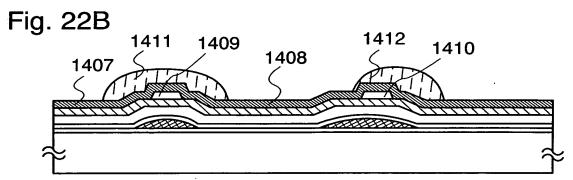


Fig. 21







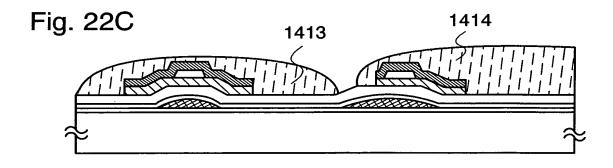


Fig. 22D

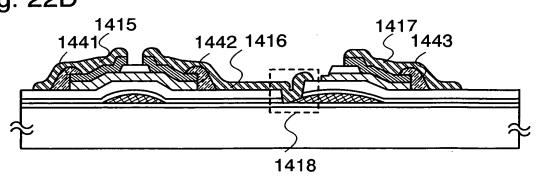


Fig. 23A

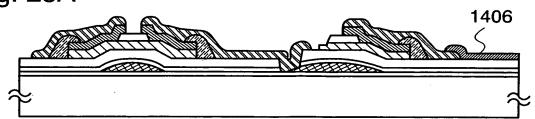
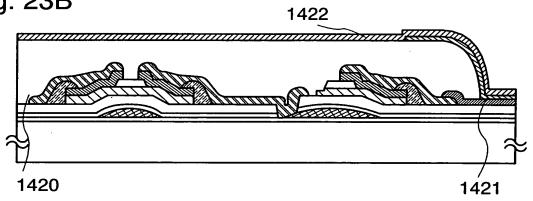
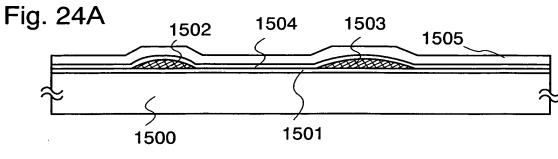
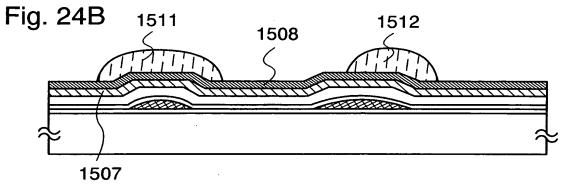


Fig. 23B







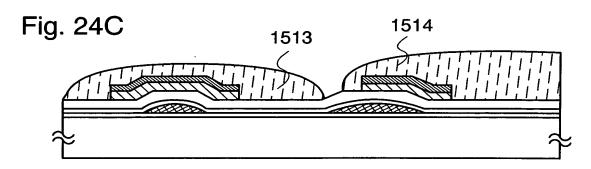
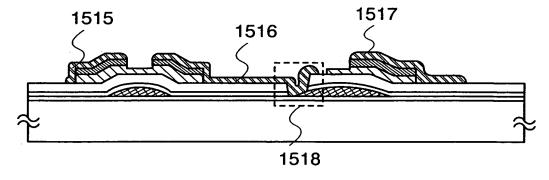
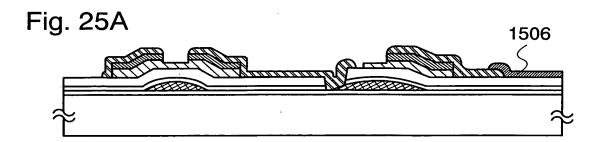


Fig. 24D





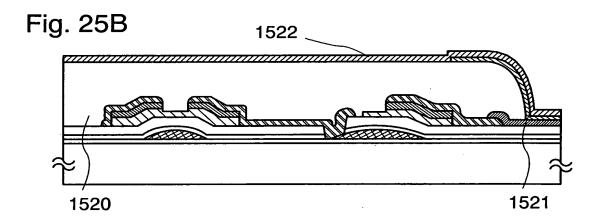


Fig. 26A

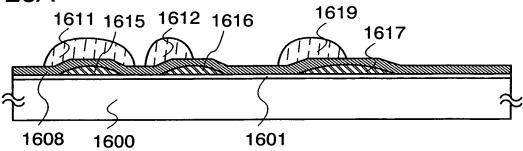


Fig. 26B

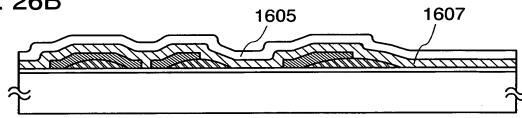


Fig. 26C

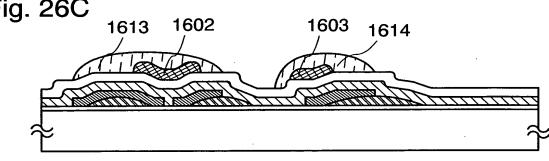


Fig. 26D

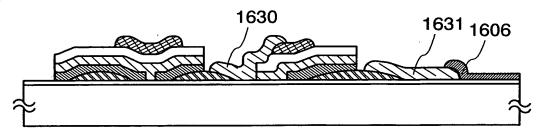


Fig. 27

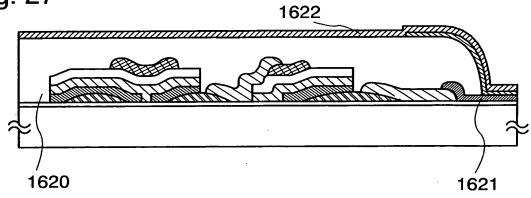
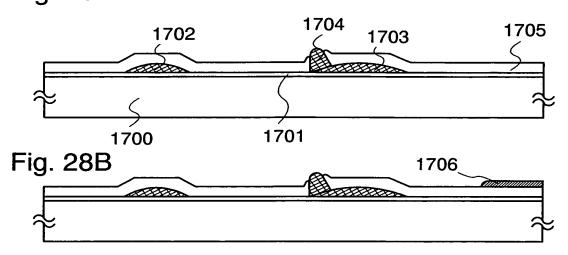


Fig. 28A



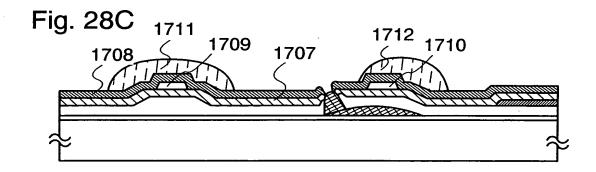


Fig. 28D

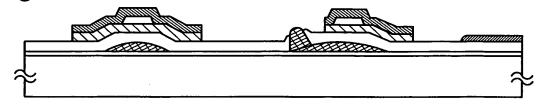


Fig. 29A

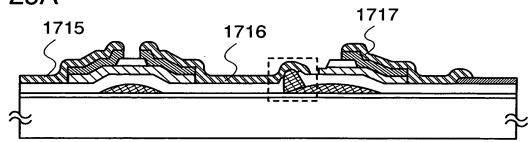
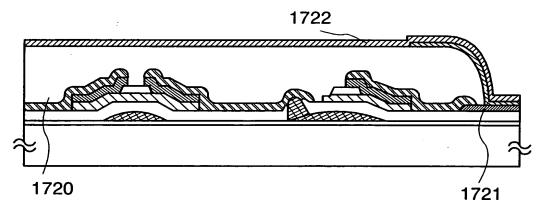


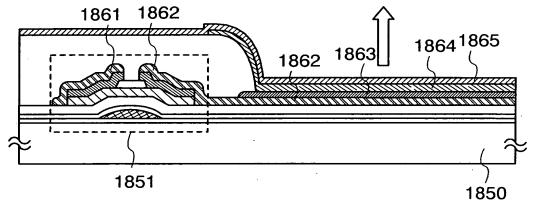
Fig. 29B



30/38 Fig. 30A 1852 1853

1851

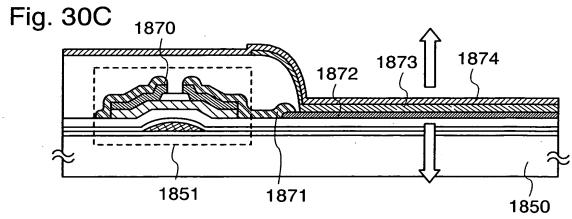
Fig. 30B



1856

1850

1855



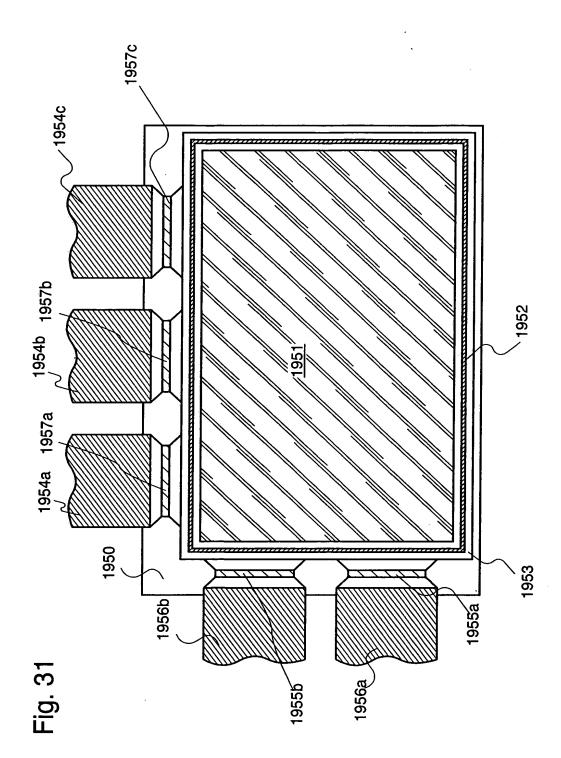
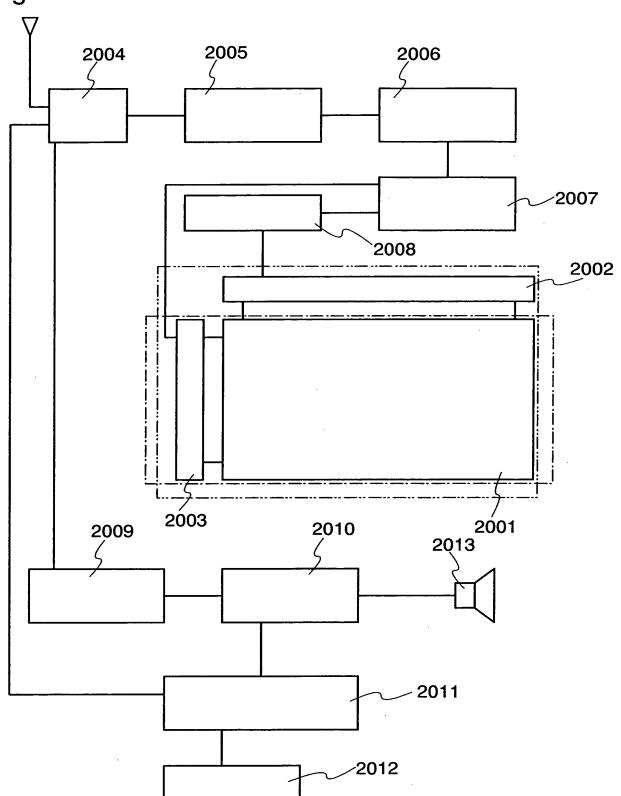


Fig. 32



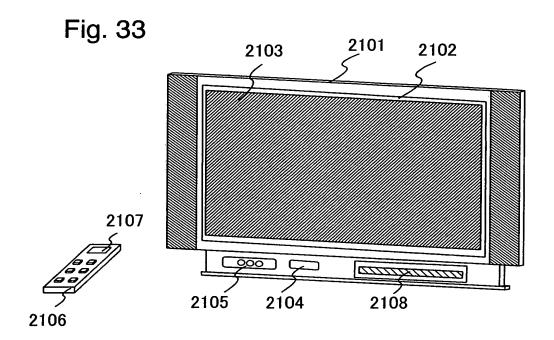


Fig. 34A

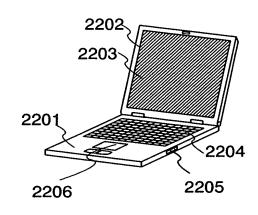


Fig. 34B

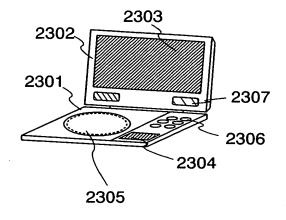
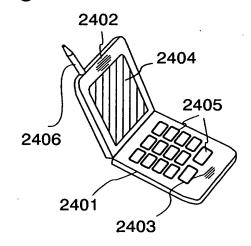


Fig. 34C



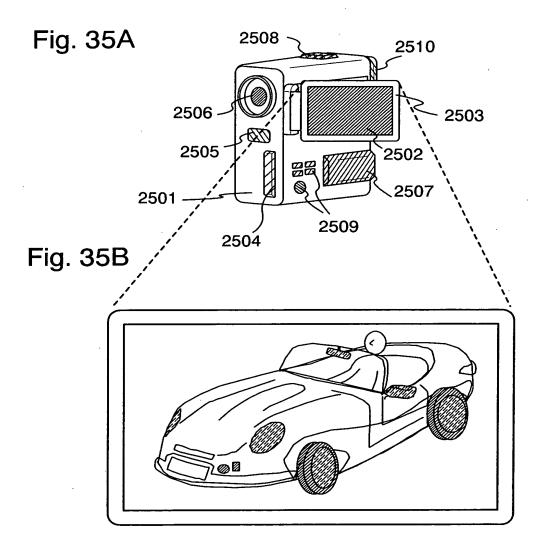
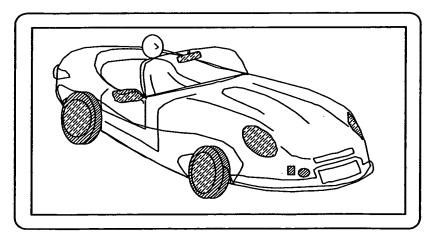


Fig. 35C



## **EXPLANATION OF REFERENCE**

100: pixel portion (display region), 101: switching TFT, 104: driving TFT, 106: EL element, 108: capacitor, 503: pixel portion (display region), 504: pixel portion (display region), 505: pixel portion (display region), 605: gate insulating layer, 606: insulating layer, 800: substrate, 801: base film, 802: conductive layer, 803: conductive layer, 804: insulating layer, 805: gate insulating layer, 806: conductive layer, 807: semiconductor layer, 808: N-type semiconductor layer, 809: channel protective film, 811: mask layer, 813: mask layer, 815: conductive layer, 816: conductive layer, 817: conductive layer, 818: through hole, 820: insulating layer, 821: electroluminescent layer, 822: conductive layer, 850: sealing substrate, 851: sealing material, 854: circuit in each pixel. 860: gate wiring layer, 861: anisotropic conductive layer, 862: flexible printed circuit (FPC), 900: substrate, 903: droplet discharging unit, 904: image pickup unit, 905: head, 907: control unit, 908: memory medium, 909, image processing unit. 910: computer, 911: marker, 954: circuit in each pixel, 1001: TFT (switching TFT), 1002: TFT (driving TFT), 1003: light emitting element (EL element), 1004: capacitor, 1005: source signal line, 1006: gate signal line, 1007: power supply line, 1054: circuit in each pixel, 1154: circuit in each pixel, 1200: substrate, 1201: base film, 1202: conductive layer, 1203: conductive layer, 1205: gate insulating layer, 1206: conductive layer, 1207: semiconductor layer, 1208: N-type semiconductor layer, 1211: mask layer, 1213: mask layer, 1215: conductive layer, 1216: conductive layer, 1217: conductive layer, 1218: through hole, 1220: insulating layer, 1221: electroluminescent layer, 1222: conductive layer, 1254: circuit in each pixel, 1300: substrate, 1301: base film, 1302: gate electrode layer, 1303: gate electrode layer, 1305: gate insulating layer, 1306: conductive layer, 1307: semiconductor layer, 1311: mask layer, 1313: mask layer, 1315: conductive layer, 1316: conductive layer, 1317: conductive layer, 1320: insulating layer, 1321: electroluminescent layer, 1322: conductive layer, 1330: conductive layer, 1331: conductive layer, 1400: substrate, 1401: base film, 1402: conductive layer, 1403: conductive layer, 1405: gate insulating layer, 1406: conductive layer, 1407: semiconductor layer, 1408: N-type semiconductor layer, 1409: channel protective film, 1411: mask layer, 1413: mask layer, 1415: conductive layer, 1416: conductive layer, 1417: conductive layer, 1418: through hole, 1420: insulating layer, 1421: electroluminescent layer, 1422: conductive l

layer, 1441: insulating layer, 1500: substrate, 1501: base film, 1502: conductive layer, 1503: conductive layer, 1505: gate insulating layer, 1506: conductive layer, 1507: semiconductor layer, 1508: N-type semiconductor layer, 1511: mask layer, 1513: mask layer, 1515: conductive layer, 1516: conductive layer, 1517: 1518: through hole, 1520: insulating layer, conductive layer, electroluminescent layer, 1522: conductive layer, 1600: substrate, 1601: base film, 1602: conductive layer, 1603: conductive layer, 1605: gate insulating layer, 1606: conductive layer, 1607: semiconductor layer, 1611: mask layer, 1613: mask layer, 1615: conductive layer, 1616: conductive layer, 1617: conductive layer, 1620: insulating layer, 1621: electroluminescent layer, 1622: conductive layer, 1630: conductive layer, 1631: conductive layer, 1700: substrate, 1701: base film, 1702: conductive layer, 1703: conductive layer, 1704: conductor, 1705: gate insulating layer, 1706: conductive layer, 1707: semiconductor layer, 1708: N-type semiconductor layer, 1709: channel protective film, 1711: mask layer, 1715: conductive layer, 1716: conductive layer, 1717: conductive layer, 1720: insulating layer, 1721: electroluminescent layer, 1722: conductive layer, 1850: substrate, 1851: transistor, 1852: source wiring or drain wiring, 1853: source wiring or drain wiring, 1854: electrode, 1855: electroluminescent layer, 1856: electrode, 1861: source wiring or drain wiring, 1862: source wiring or drain wiring, 1863; electrode, 1864; electroluminescent layer, 1865; electrode, 1870; source wiring or drain wiring, 1871: source wiring or drain wiring, 1872: electrode, 1873: electroluminescent layer, 1874: electrode, 1950: substrate, 1951: pixel portion, 1952: sealing material, 1953: counter substrate, 1954a: FPC, 1954b: FPC, 1954c: FPC, 1955a: driver IC, 1955b: driver IC, 1956a: FPC, 1956b: FPC, 1957a: driver IC, 1957b: driver IC, 1957c: driver IC, 2001: EL display panel, 2002: source signal line driver circuit, 2003: a gate signal line driver circuit, 2004: tuner, 2005: video signal amplifier circuit, 2007: control circuit, 2008: signal divider circuit, 2009: audio signal amplifier circuit, 2010: audio signal amplifier circuit, 2011: control circuit, 2012: input portion, 2013: speaker, 2021: display screen, 2022: speaker, 2024: operating switch, 2101: housing, 2102: display panel, 2103: main screen, 2104: modem, 2105: receiver, 2106: remote control unit, 2107: display portion, 2108: sub-display, 2201: main body, 2202: housing, 2203: display portion, 2204: keyboard, 2205: external connecting port, 2206: pointing mouse, 2301: main body, 2302: housing, 2303: display portion A, 2304:

display portion B, 2306: operating key, 2307: speaker portion, 2401: main body, 2402: audio output portion, 2403: audio input portion, 2404: display portion, 2405: operating switches, 2406: antenna, 2501: main body, 2502: display portion, 2503: housing, 2504: external connecting port, 2505: remote control receiving portion, 2506: receiving portion, 2507: battery, 2508: audio input portion, 2509: operating keys